



**ELECTRONIC COPY**

LG630464079  
Report verification at igi.org



April 30, 2024

IGI Report Number **LG630464079**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **MARQUISE BRILLIANT**

Measurements **10.08 X 5.42 X 3.43 MM**

**GRADING RESULTS**

Carat Weight **1.05 CARAT**

Color Grade **D**

Clarity Grade **VVS 2**

April 30, 2024  
IGI Report Number **LG630464079**  
Description **LABORATORY GROWN DIAMOND**  
Shape and Cutting Style **MARQUISE BRILLIANT**  
Measurements **10.08 X 5.42 X 3.43 MM**

**GRADING RESULTS**

Carat Weight **1.05 CARAT**

Color Grade **D**

Clarity Grade **VVS 2**

**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **EXCELLENT**

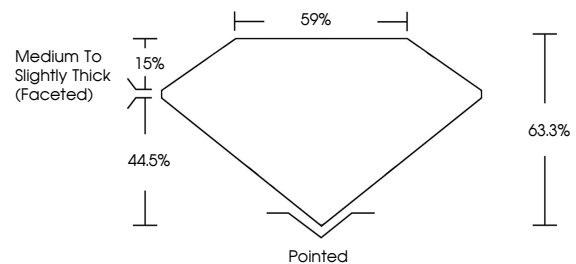
Fluorescence **NONE**

Inscription(s) **IGI LG630464079**

Comments: As Grown - No indication of post-growth treatment.

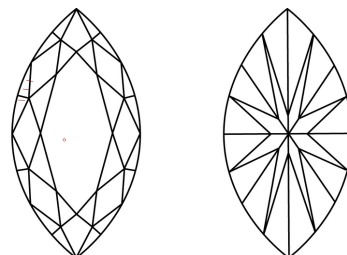
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

**PROPORTIONS**



Sample Image Used

**CLARITY CHARACTERISTICS**



**KEY TO SYMBOLS**

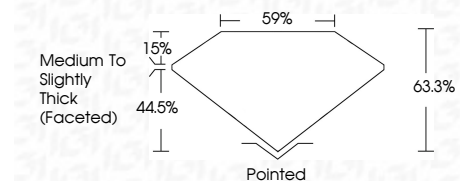
Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.

**COLOR**

D E F G H I J Faint Very Light Light

**CLARITY**

IF	VS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	I <sup>1-3</sup>
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **EXCELLENT**

Fluorescence **NONE**

Inscription(s) **IGI LG630464079**

Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II



**IGI**

April 30, 2024  
IGI Report No LG630464079  
MARQUISE BRILLIANT

10.08 X 5.42 X 3.43 MM

1.05 CARAT  
D

VVS 2  
D

63.3%  
59%

Medium to Slightly Thick (Faceted)

Pointed  
EXCELLENT  
EXCELLENT  
NONE  
IGI LG630464079

Comments: As Grown - No indication of post-growth treatment. This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II